NSN 5961-00-119-3548

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Inclosure Material:

Metal

Overall Length:

0.455 inches

Mounting Facility Quantity:

1

Internal Configuration:

Junction contact

Electrode Internally-electrically Connected To Case:

Collector

Internal Junction Configuration:

Pnp

Mounting Method:

Threaded stud

Features Provided:

Hermetically sealed case

Overall Width Across Flats:

0.510 inches

Thread Size:

0.190 inches

Semiconductor Material:

Germanium

Voltage Rating In Volts Per Characteristic:

70.0 breakdown voltage, collector-to-base, emitter open and 20.0 breakdown voltage, emitter-to-base, collector open and 70.0

breakdown voltage, collector-to-emitter, base open

Current Rating Per Characteristic:

3.00 amperes source cutoff current and 1.00 amperes base current, dc

Power Rating Per Characteristic:

15.0 watts small-signal input power, common-collector

Maximum Operating Tempurature Per Measurement Point:

100.0 degrees celsius case

Thread Series Designator:

Unf

Terminal Type And Quantity:

3 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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